

# XN01116 (XN1116)

## Silicon PNP epitaxial planar type

For switching/digital circuits

### ■ Features

- Two elements incorporated into one package  
(Emitter-coupled transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half

### ■ Basic Part Number

- UNR2116 (UN2116) × 2

### ■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

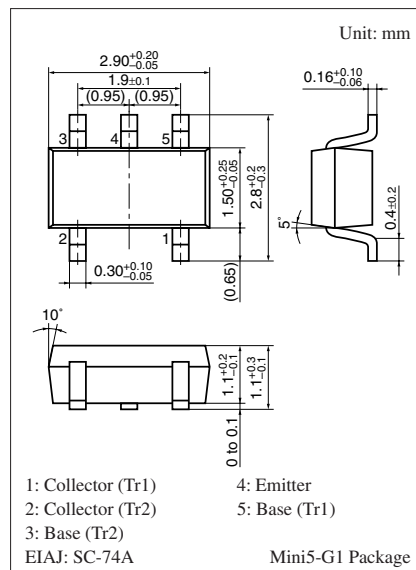
Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	$V_{\text{CBO}}$	-50	V
Collector-emitter voltage (Base open)	$V_{\text{CEO}}$	-50	V
Collector current	$I_{\text{C}}$	-100	mA
Total power dissipation	$P_{\text{T}}$	300	mW
Junction temperature	$T_{\text{j}}$	150	$^\circ\text{C}$
Storage temperature	$T_{\text{stg}}$	-55 to +150	$^\circ\text{C}$

### ■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	$V_{\text{CBO}}$	$I_{\text{C}} = -10 \mu\text{A}$ , $I_{\text{E}} = 0$	-50			V
Collector-emitter voltage (Base open)	$V_{\text{CEO}}$	$I_{\text{C}} = -2 \text{mA}$ , $I_{\text{B}} = 0$	-50			V
Collector-base cutoff current (Emitter open)	$I_{\text{CBO}}$	$V_{\text{CB}} = -50 \text{V}$ , $I_{\text{E}} = 0$			-0.1	$\mu\text{A}$
Collector-emitter cutoff current (Base open)	$I_{\text{CEO}}$	$V_{\text{CE}} = -50 \text{V}$ , $I_{\text{B}} = 0$			-0.5	$\mu\text{A}$
Emitter-base cutoff current (Collector open)	$I_{\text{EBO}}$	$V_{\text{EB}} = -6 \text{V}$ , $I_{\text{C}} = 0$			-0.01	mA
Forward current transfer ratio	$h_{\text{FE}}$	$V_{\text{CE}} = -10 \text{V}$ , $I_{\text{C}} = -5 \text{mA}$	160		460	—
$h_{\text{FE}}$ Ratio *	$h_{\text{FE}}(\text{Small}/\text{Large})$	$V_{\text{CE}} = -10 \text{V}$ , $I_{\text{C}} = -5 \text{mA}$	0.50	0.99		—
Collector-emitter saturation voltage	$V_{\text{CE(sat)}}$	$I_{\text{C}} = -10 \text{mA}$ , $I_{\text{B}} = -0.3 \text{mA}$			-0.25	V
Output voltage high-level	$V_{\text{OH}}$	$V_{\text{CC}} = -5 \text{V}$ , $V_{\text{B}} = -0.5 \text{V}$ , $R_{\text{L}} = 1 \text{k}\Omega$	-4.9			V
Output voltage low-level	$V_{\text{OL}}$	$V_{\text{CC}} = -5 \text{V}$ , $V_{\text{B}} = -2.5 \text{V}$ , $R_{\text{L}} = 1 \text{k}\Omega$			-0.2	V
Input resistance	$R_{\text{I}}$		-30%	4.7	+30%	$\text{k}\Omega$
Transition frequency	$f_{\text{T}}$	$V_{\text{CB}} = -10 \text{V}$ , $I_{\text{E}} = 1 \text{mA}$ , $f = 200 \text{MHz}$		80		MHz

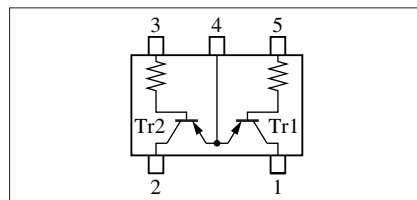
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*: Ratio between 2 elements

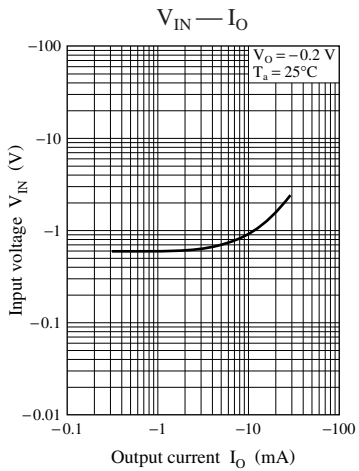
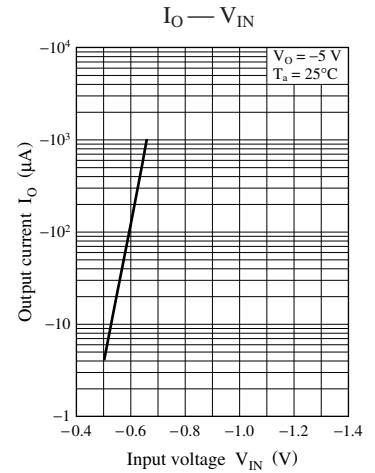
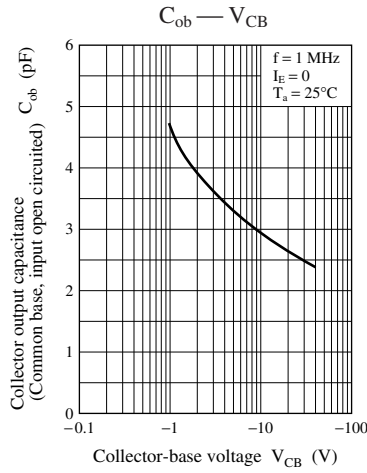
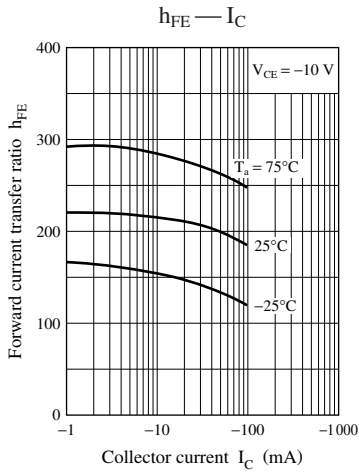
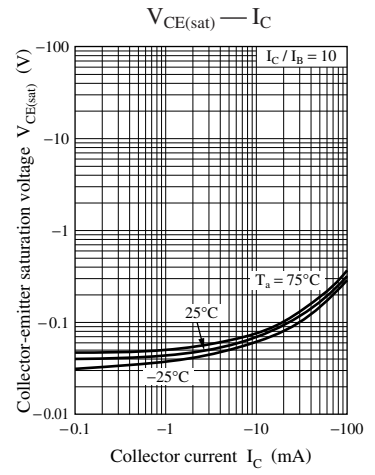
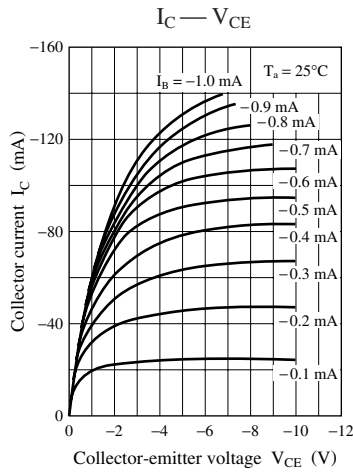
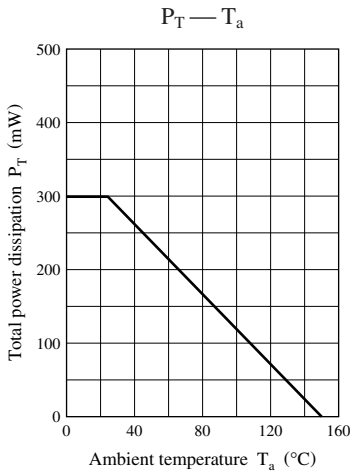


Marking Symbol: 7N

Internal Connection



Note) The part number in the parenthesis shows conventional part number.



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